



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of:

Geum-Jong BAE, et al

Art Unit: 2814

Serial No. 10/659,384

Examiner: H.V. Pham

(Division of Serial No. 10/274,035)

Filed: September 11, 2003

*Confirmation No.* 3795

For: MOS TRANSISTOR HAVING A T-SHAPED  
GATE ELECTRODE AND METHOD FOR  
FABRICATING THE SAME

Attorney Docket No. 239/169 DIV

**AMENDMENT UNDER 37 C.F.R. § 1.114**

Mail Stop: Amendments  
Commissioner for Patents  
United States Patent and Trademark Office  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**INTRODUCTORY COMMENTS**

In connection with the Request for Continued Examination filed concurrently herewith, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

**Amendments to the Claims** are reflected in a listing of claims, which begins on page 2 of this paper.

**Remarks** begin on page 6 of this paper.